TOSHIBA VARIABLE CAPACITANCE DIODE SILICON EPITAXIAL PLANAR TYPE

1 S V 2 2 8

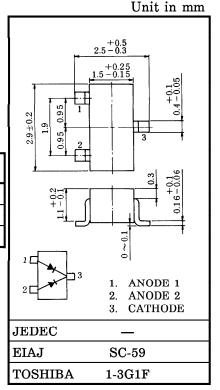
ELECTRONIC TUNING APPLICATIONS OF FM RECEIVERS.

• Low $r_S : r_S = 0.3\Omega$ (Typ.)

Small Package

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	$v_{ m R}$	15	V
Junction Temperature	$\mathbf{T}_{\mathbf{j}}$	125	°C
Storage Temperature	$\mathrm{T_{stg}}$	-55~125	°C



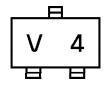
Weight: 0.13g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Reverse Voltage	v_{R}	$I_R = 10 \mu A$		15	_	_	V
Reverse Current	$ _{ m I_R}$	$V_{R}=15V$				10	nA
Capacitance	C_{3V}	V_R =3V, f=1MHz (No	te)	28.5	30.5	32.5	pF
Capacitance	C_{8V}	$V_R = 8V$, $f = 1MHz$ (No	te)	11.7	12.7	13.7	рF
Capacitance Ratio	C_{3V}/C_{8V}	— (No	te)	2.1	1	2.6	_
Series Resistance	r_{s}	V_R =3V, f=100MHz (No	te)	_	0.3	0.5	Ω

(Note): Characteristics between Anode 1 and Anode 2

Marking



961001EAA2

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Table 1: ADDRESS CLASSIFICATION OF CAPACITANCE TEST CONDITION : f = 1MHz, Ta = 25°C

No.	C_{2V}	$\mathrm{C}_{3\mathrm{V}}$	$\mathrm{C_{6V}}$	$\mathrm{c}_{8\mathrm{V}}$
1	34.70~35.74	28.60~29.45	16.80~17.30	11.72~12.07
2	35.56~36.62	29.31~30.18	17.21~17.72	12.01~12.37
3	36.44~37.53	30.03~30.93	17.63~18.15	12.31~12.67
4	37.35~38.47	30.77~31.69	18.06~18.60	12.61~12.98
5	38.27~39.41	31.53~32.47	18.50~19.05	12.92~13.30
6	_	_	18.95~19.51	13.23~13.62

(1) Units are compounded in one package and are matched to 3%.

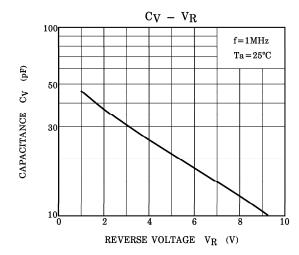
$$\frac{\text{C (Max.)-C (Min.)}}{\text{C (Min.)}} \leq 0.03 \text{ (V}_{\text{R}} = 2 \sim 8 \text{V)}$$

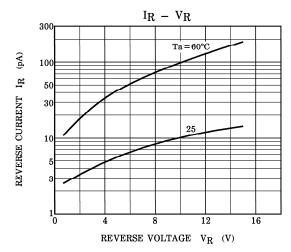
and capacitance is classified as Table 1.

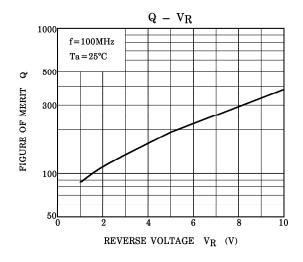
- C2V, C3V, C6V, C8V are A1-A2 capacitance. (2)
- The tolerance of address is ± 1 address. (3)

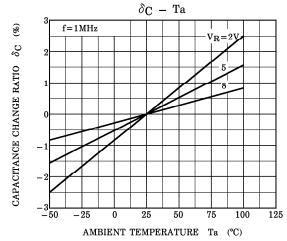
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NOTE:
$$\delta_{\rm C}$$
 (%) = $\frac{{\rm C} ({\rm Ta}) - {\rm C} (25)}{{\rm C} (25)} \times 100$